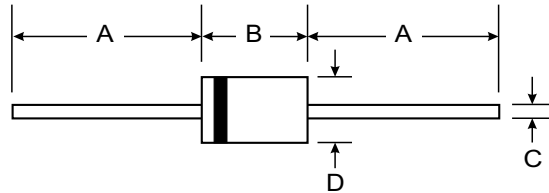


Features

- Glass Passivated Die Construction
- Diffused Junction
- Ultra-Fast Switching for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 30A Peak
- Low Reverse Leakage Current
- Plastic Material: UL Flammability Classification Rating 94V-0



Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Marking: Type Number
- Weight: 0.35 grams (approx.)
- Mounting Position: Any

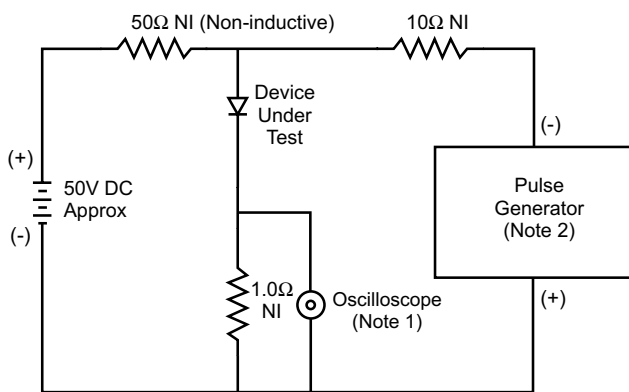
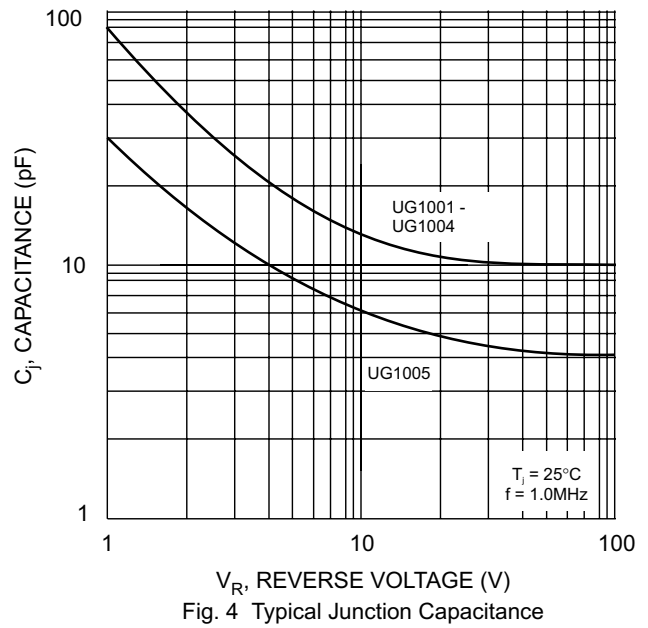
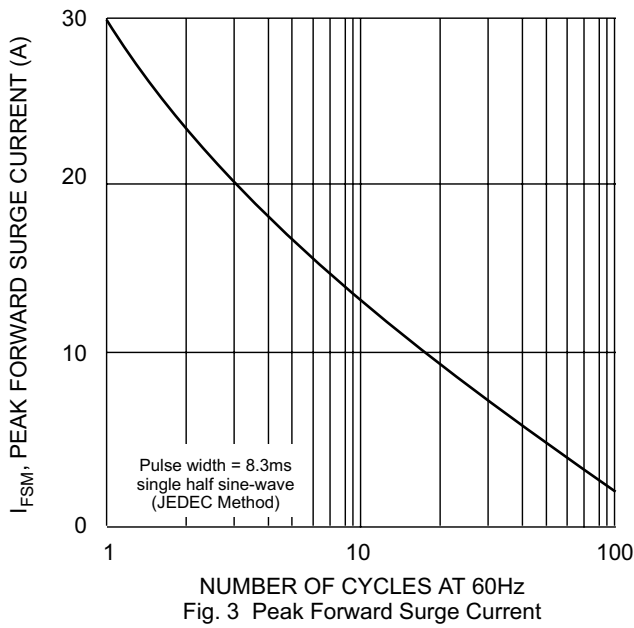
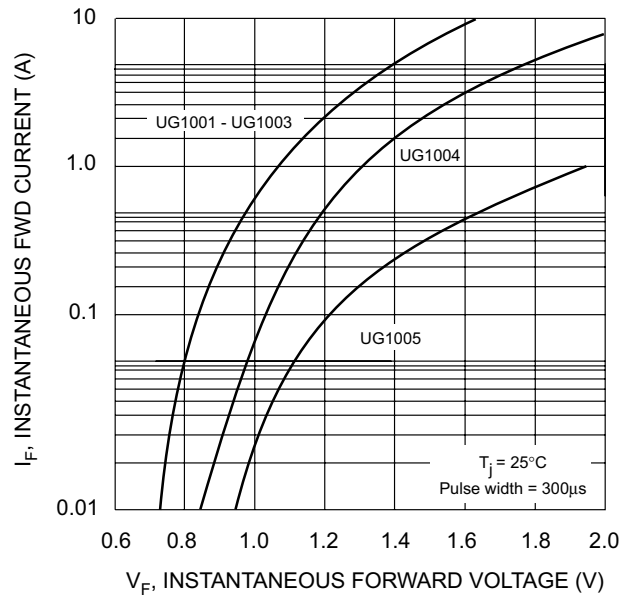
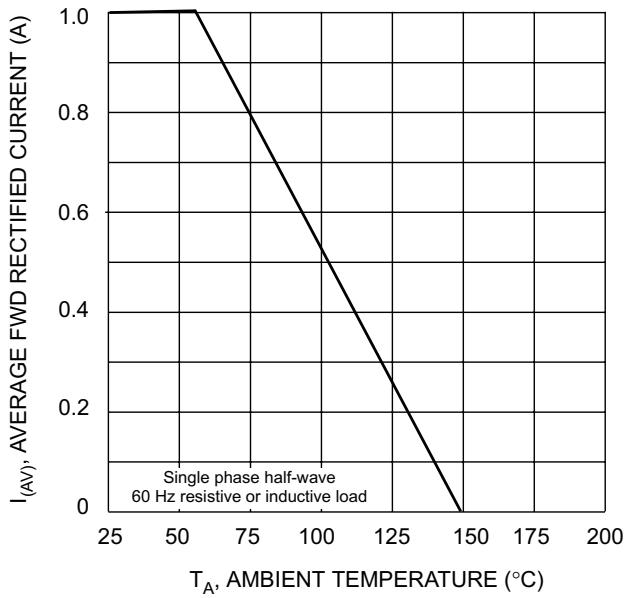
| DO-41 | | |
|----------------------|-------|-------|
| Dim | Min | Max |
| A | 25.40 | — |
| B | 4.06 | 5.21 |
| C | 0.71 | 0.864 |
| D | 2.00 | 2.72 |
| All Dimensions in mm | | |

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

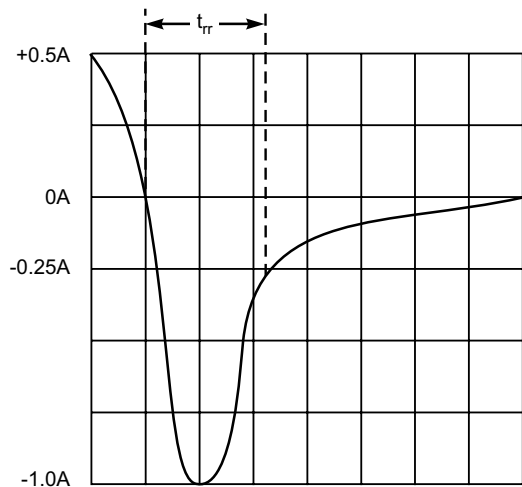
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

| Characteristic | Symbol | UG1001 | UG1002 | UG1003 | UG1004 | UG1005 | Unit |
|---|-----------------------------------|--------------------------|--------|--------|--------|--------|------|
| Peak Repetitive Reverse Voltage | V _{RRM} | 50 | 100 | 200 | 400 | 600 | V |
| Working Peak Reverse Voltage | V _{RWM} | | | | | | |
| DC Blocking Voltage | V _R | | | | | | |
| RMS Reverse Voltage | V _{R(RMS)} | 35 | 70 | 140 | 280 | 420 | V |
| Average Rectified Output Current (Note 1) | I _o | 1.0 | | | | | A |
| | | @ T _A = 55°C | | | | | |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on Rated Load (JEDEC Method) | I _{FSM} | 30 | | | | | A |
| Forward Voltage | V _{FM} | 1.0 | | | 1.3 | 1.7 | V |
| | | @ I _F = 1.0A | | | | | |
| Peak Reverse Current | I _{RM} | 5.0 | | | | | μA |
| | | @ T _A = 25°C | | | | | |
| | | @ T _A = 100°C | | | | | |
| Reverse Recovery Time (Note 3) | t _{rr} | 50 | | | | 75 | ns |
| Typical Junction Capacitance (Note 2) | C _j | 20 | | | | 10 | pF |
| Typical Thermal Resistance Junction to Ambient | R _{θJA} | 95 | | | | | K/W |
| Operating and Storage Temperature Range | T _j , T _{STG} | -65 to +150 | | | | | °C |

- Notes:
1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. See figure 5.



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.



Set time base for 50/100 ns/cm

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit